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Surfactant Mediated Synthesis of Bismuth Selenide Thin Films For Photoelectrochemical Solar Cell

Applications

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Abstract

In the present report, nanostructured bismuth selenide (Bi₂Se₃) thin films have been successfully

deposited by using arrested precipitation technique (APT) at room temperature. The effect of three different

surfactants on the optostructural, morphological, compositional and photoelectrochemical properties of Bi₂Se₃

thin films were investigated. Optical absorption data indicates direct and allowed transition with a band gap

energy varied from 1.4 eV to 1.8 eV. The X-ray diffraction pattern (XRD) revealed that Bi₂Se₃ thin films are

crystalline in nature and confirmed rhombohedral crystal structure.SEM micrographs shows morphological

transition from interconnected mesh to nanospheres like and finally granular morphology. Surface topography

of Bi₂Se₃ thin films was determined by AFM. Compositional analysis of all samples was carried out by energy

dispersive X-ray spectroscopy (EDS). Finally, all Bi₂Se₃ thin films shows good PEC performance with highest

photoconversion efficiency 1.47%. In order to study the stability of Bi2Se3 thin films four cycles are repeated

after gap of one week each. Further PEC performance of all Bi₂Se₃ thin films are also supported by

electrochemical impedance (EIS) measurement study.

Keywords:- thin films, APT, effect of surfactant, 1.47 % PEC

1. Introduction:-

Today the main problem in front of society is energy crisis. To overcome this problem all scientific

community is currently working on the renewable and sustainable energy sources i.e. photovoltaic energy [1].

The thin films have strong phonon scattering interactions at the surfaces and lower thermal conductivity than

those of bulk materials. The cost effective fabrication and ease of contact with redox electrolyte make thin films

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